

NPN Triple Diffused Planar Silicon Transistor

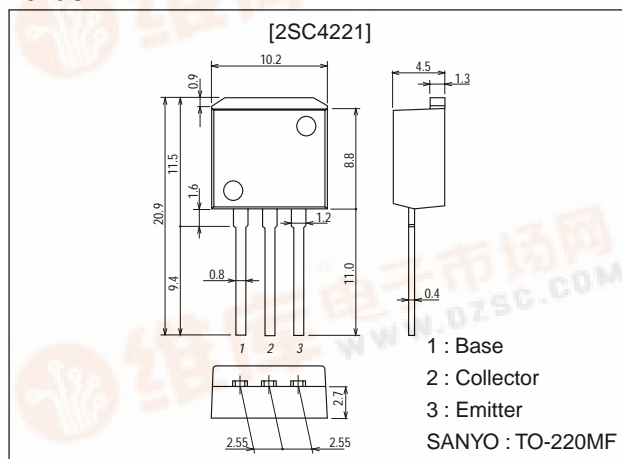
SANYO**2SC4221****500V/3A Switching Regulator Applications****Features**

- High breakdown voltage, high reliability.
- Fast switching speed ($t_f=0.1\mu s$ typ).
- Wide ASO.
- Adoption of MBIT process.
- Suitable for sets whose height is restricted.

Package Dimensions

unit:mm

2049C

**Specifications****Absolute Maximum Ratings at $T_a = 25^\circ C$**

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		800	V
Collector-to-Emitter Voltage	V_{CEO}		500	V
Emitter-to-Base Voltage	V_{EBO}		7	V
Collector Current	I_C		3	A
Collector Current (Pulse)	I_{CP}	$PW \leq 300\mu s$, duty cycle $\leq 10\%$	6	A
Base Current	I_B		1	A
Collector Dissipation	P_C	$T_c = 25^\circ C$	40	W
Junction Temperature	T_j		150	$^\circ C$
Storage Temperature	T_{stg}		-55 to +150	$^\circ C$

Electrical Characteristics at $T_a = 25^\circ C$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=500V$, $I_E=0$			10	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=5V$, $I_C=0$			10	μA
DC Current Gain	h_{FE1}^*	$V_{CE}=5V$, $I_C=0.3A$	15		50	
	h_{FE2}	$V_{CE}=5V$, $I_C=1.5A$	8			

* : The h_{FE1} of the 2SC4221 is classified as follows. When specifying the h_{FE1} rank, specify two ranks or more in principle.

15	L	30	20	M	40	30	N	50
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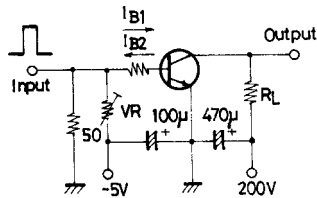
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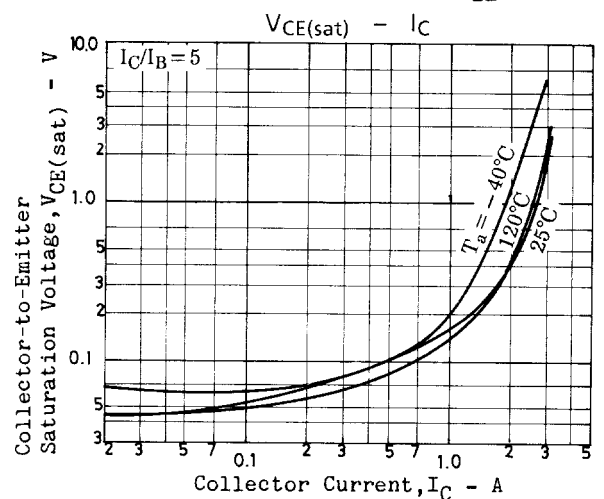
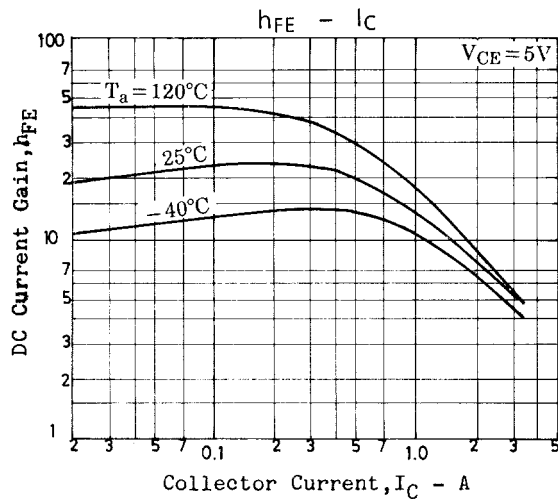
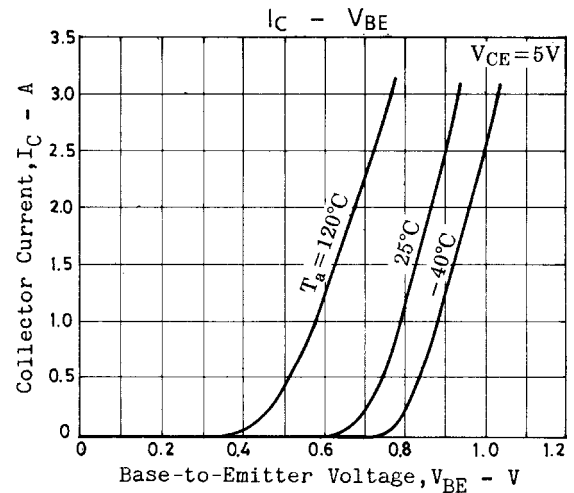
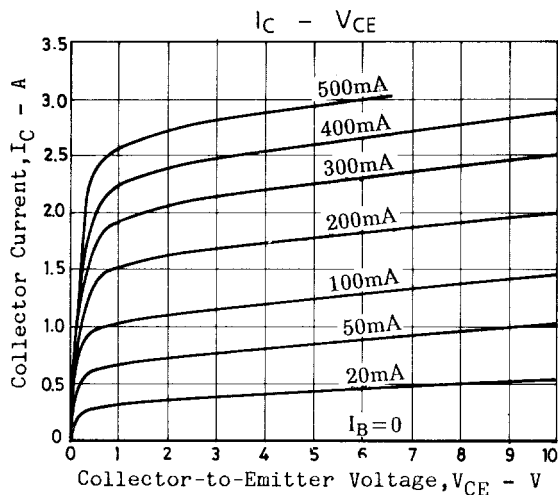
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=1.5A, I_B=0.3A$			1.0	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=1.5A, I_B=0.3A$			1.5	V
Gain-Bandwidth Product	f_T	$V_{CE}=10V, I_C=0.3A$		18		MHz
Output Capacitance	C_{ob}	$V_{CB}=10V, f=1MHz$		50		pF
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=1mA, I_E=0$	800			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=5mA, R_{BE}=\infty$	500			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=1mA, I_C=0$	7			V
Collector-to-Emitter Sustain Voltage	$V_{CEX(sus)}$	$I_C=1.5A, I_{B1}=0.6A, L=2mH, I_{B2}=-0.6A$, clamped	500			V
Turn-ON Time	t_{on}	$I_C=2A, I_{B1}=0.4A, I_{B2}=-0.8A, R_L=100\Omega, V_{CC}=200V$			0.5	μs
Storage Time	t_{stg}	$I_C=2A, I_{B1}=0.4A, I_{B2}=-0.8A, R_L=100\Omega, V_{CC}=200V$			3.0	μs
Fall Time	t_f	$I_C=2A, I_{B1}=0.4A, I_{B2}=-0.8A, R_L=100\Omega, V_{CC}=200V$			0.3	μs

Switching Time Test Circuit

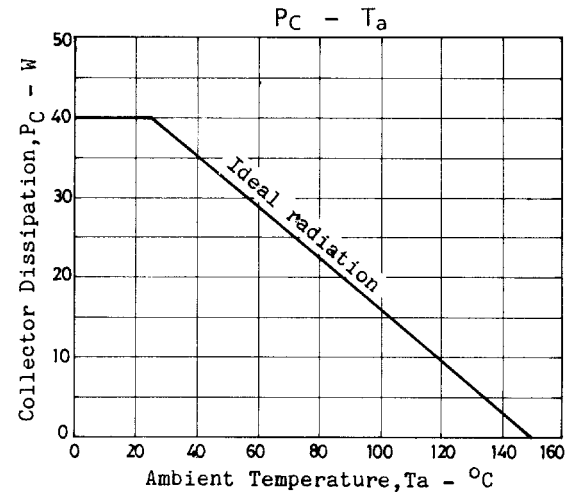
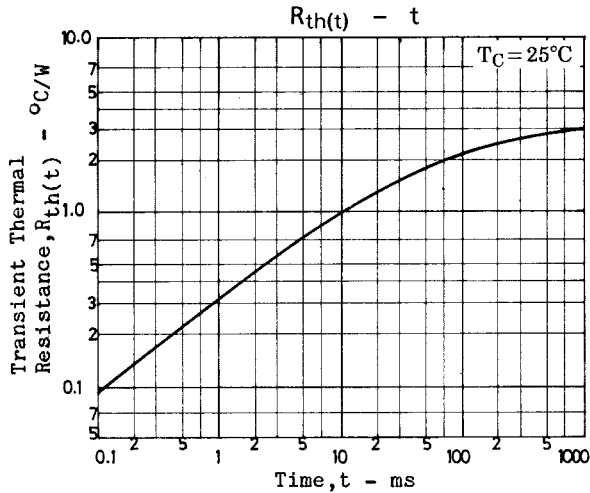
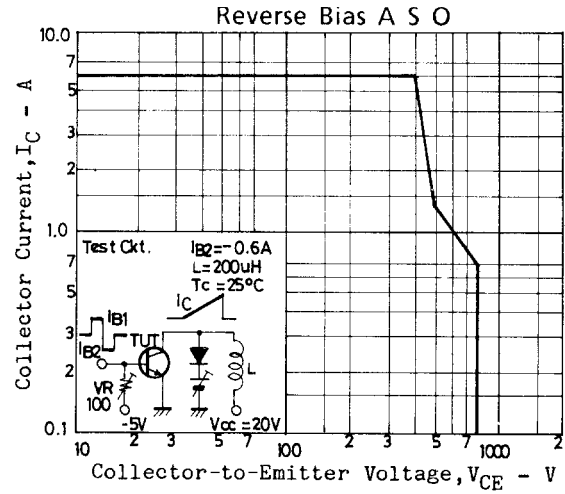
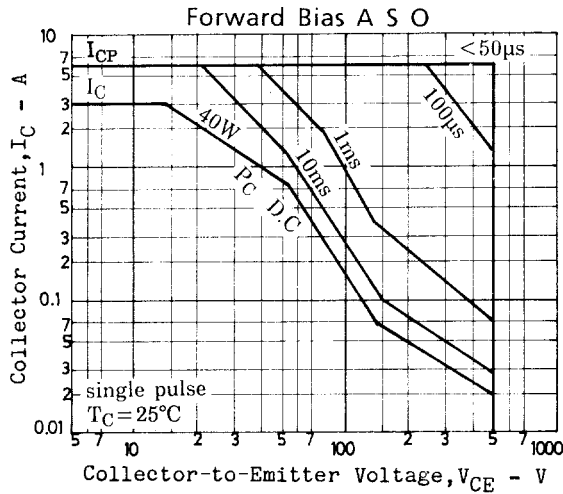
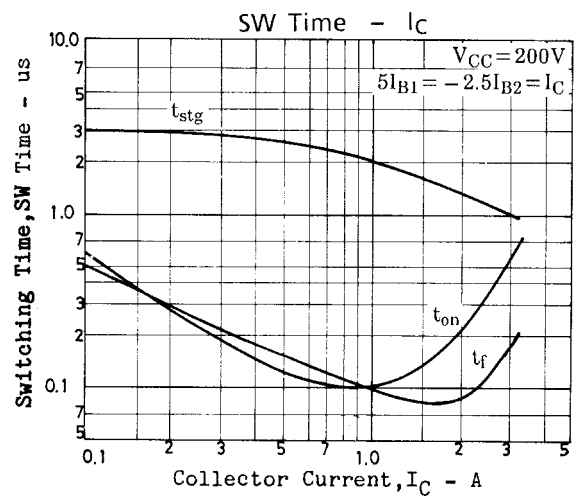
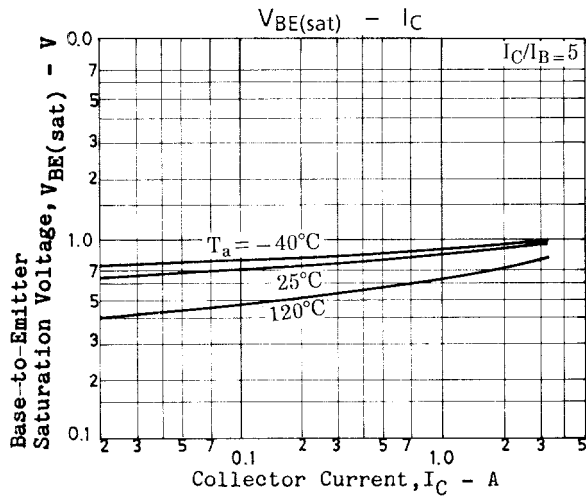


PW = 20 μs , Duty Cycle $\leq 1\%$

Unit (resistance: Ω , capacitance: F)



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